NSN 5961-01-463-0611

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Inclosure Material:

Glass

Overall Length:

1.400 millimeters

End Application:

6625-01-425-2551

Mounting Facility Quantity:

3

Mounting Method:

Terminal

Semiconductor Material:

Silicon alloy

Voltage Rating In Volts Per Characteristic:

-15.0 collector to base voltage/static/emitter open and -15.0 collector-to-emitter, substaining voltage, base open-circuited and -4.5 emitter

to base voltage, static, collector open

Current Rating Per Characteristic:

Between -50.00 milliamperes source cutoff current and -100.00 nanoamperes source cutoff current and -100.00 nanoamperes source cutoff current universal

Power Rating Per Characteristic:

200.0 milliwatts small-signal input power, common-emitter absolute

Maximum Operating Tempurature Per Measurement Point:

150.0 degrees celsius junction

Terminal Type And Quantity:

3 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

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